NSN 5962-01-192-0210

Memory Microcircuit - Page 1 of 1



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Body Length:

31.75 millimeters

Body Width:

14.66 millimeters

Body Height:

5.51 millimeters

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and high speed and low power and w/enable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

22 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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